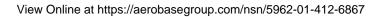
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Memory Microcircuit - Page 1 of 1





## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

### **Terminal Surface Treatment:**

Solder

## Product Name:

Programmed

## Voltage Rating And Type Per Characteristic:

6.5 volts power source

#### **Time Rating Per Chacteristic:**

200.00 nanoseconds delay

#### Memory Device Type:

Eprom

#### Terminal Type And Quantity:

28 printed circuit

## Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

#### Fiig:

A458a0